

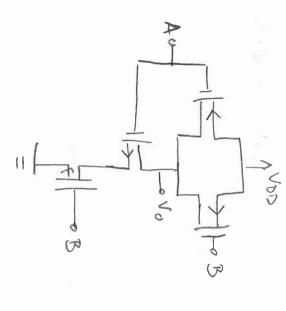
OT & ID > 8,02x52 UPD = 12V 1 by Nos > Ves - N+ garther " No= 0.11+8+10.11+8-4.003. (-0.68) Sup JAT => ID = K (VGS -V+)2 = K (VB - V+)2 = 0.24.10 (VB-3)2/d 4-3V K=0.48-1034/VZ 340.0 1 + S+W.0 MOSFET: IC =0 => VC=VD = VDD - IDRA 12-40 2.103 2,003 => 12-VD = 2:19 0.24.10 (VD-3) - 0.48 VD+4.32-- 1 -0.16 V 6.42 V -> NOS = 6.42 V > 6.42 V -3 V > OV VS =0 3450 04 Pro.0 1 7 StW 0 -> In - VDD - VD ₹° SATI CN

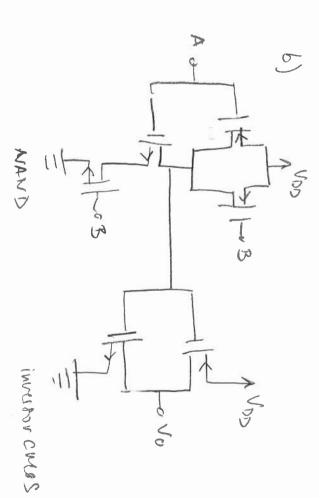
12-6.42

- 2, 29.10 A = 2, 79 mt.

> VDS = -0.16 = Vas < VT -> 07F.

2.103





c) (results ou movale): f=A.3+C

A.O. ideal - V+ = V-

$$\frac{2}{2} = \frac{2}{2} + \frac{2}{2} = \frac{1}{2} = \frac{1}$$

$$\frac{2^{-1}}{2^{-1}} = \frac{2c_{1}^{-1}}{2c_{2}^{-1}} + \frac{2c_{1}^{-1}}{2e_{1}} = \frac{3\omega c_{1} + \frac{1}{2c_{2}}}{\frac{1}{2c_{2}}} = \left(\frac{16d \cdot 10^{2} + 10^{2}}{10^{2} + 10^{2}}\right) \Omega^{-1} \Rightarrow \left| \frac{1}{2c_{1}} \right| \frac{1}{10^{2} + 16c_{10}} \Omega^{-1} = \frac{1}$$

vo(E) = 10 e jo.39 è 2mot

= 10 sen (2000 + 3.19 )V

ap: Vs = +2.5 V | IVes / > (V+) ON / Kn = Kp = 1 MA/V2 @N . VSN = -2.5V VDP = VDN / [VDS < |V&S | - N+) LIN VTN = - VTP - AV Vap - Van CD 11 NDD 143 1+N-120NI < 120VI VOS >UT QU NOS AVOS-VT LIV VDS > VOS- VT SAT

a) Uz = +2.5 V -> Vav = Vap = +2.5 V · SUP. BAT: IDN = 1/2 (VES - VT)2 Op: Vas = Vap-Vsp = +2.5V - 2.5V =OV </ Np) QN: VOS - VON-VON - 2.5 - (-2.5) - 5V > VTN-IV - +AV -> Qp OFF.

· Sup LIN: ID = [2(VGS-VI)VDS-VDS] = 0.5.103 [2.4 VDS-VDS] = VD (> IN = K (S-A) = 0.5 mA . 1642 = 2 mA. - HON 1 41 1 50-0 10KSZ \$ 18 - -8.10-3.104 V= - 80N = NON -VPS- -20- (-2.5) -- 75 V V VGS-V-

-- Vp = 104. 0 5.103 [8(Vb+2.5) - (Vp+2.5)2] = 5 [8Vb+20 - [Vb+6.25+5Vb)]=

= 5[3VD + 13.75 - VD] = 15VD - 5VD - 5VD + 62.75 -> | 5VD - 16VD - 62.75 = 0

(y)

>5 V2-16V0-68:75-0 => NPN- DNDN/2-2:04V - NDN1-12N - 2.44-(-2:5) -0:06VC

> VDS =0.06 V (perments of MSNCC NOSN.